

TC74HC7640AP/AF

TC74HC7643AP/AF

TC74HC7645AP/AF

OCTAL BUS TRANSCEIVER (WITH SCHMITT TRIGGER INPUTS)

TC74HC7640AP/AF 3-STATE INVERTING

TC74HC7643AP/AF 3-STATE INVERTING AND NON-INVERTING

TC74HC7645AP/AF 3-STATE, NON-INVERTING

The TC74HC7640A, 7643A and 7645A are high speed CMOS OCTAL BUS TRANSCEIVERS fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent LS-TTL while maintaining the CMOS low power dissipation.

The TC74HC7640A, 7643A and 7645A have the same configuration and function as the TC74HC640A, 643A and 245A respectively. They differ in that the former have Schmitt trigger inputs, making them ideal for such applications as line receivers, etc.

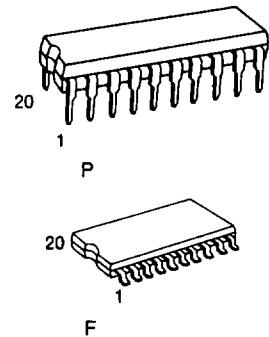
They are intended for two-way asynchronous communication between data busses. The direction of data transmission is determined by the level of the Direction (DIR) input.

The Enable (\bar{G}) input can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

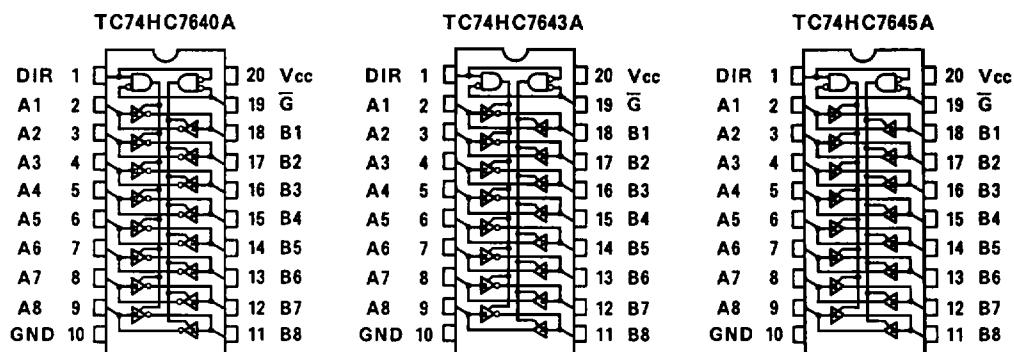
- High Speed $t_{PD}=14\text{ns}(\text{typ.})$ at $V_{CC}=5\text{V}$
- Low Power Dissipation $I_{CC}=4\mu\text{A}(\text{Max.})$ at $T_a=25^\circ\text{C}$
- High Noise Immunity $V_{NH}=V_{NL} 28\% V_{CC}(\text{Min.})$
- Output Drive Capability 15 LS-TTL Loads
- Symmetrical Output Impedance $|I_{OH}|=I_{OL}=6\text{mA}(\text{Min.})$
- Balanced Propagation Delays $t_{PLH}=t_{PHL}$
- Wide Operating Voltage Range $V_{CC}(\text{opr.})=2\text{V}\sim6\text{V}$
- Pin and Function Compatible with 74LS640, 643, 245



APPLICATION NOTES

- 1) Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.
- 2) All floating (high impedance) bus terminals must have their input levels fixed by means of pull up or pull down resistors or bus terminator IC's such as the TOSHIBA TC40117BP.

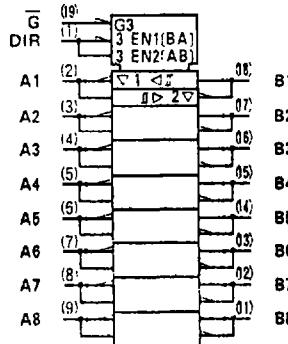
PIN ASSIGNMENT(TOP VIEW)



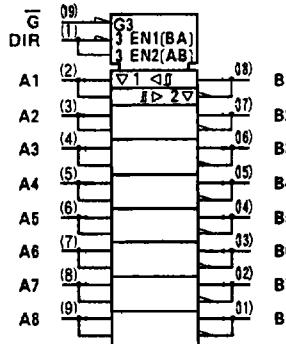
TC74HC7640AP/AF 7643AP/AF 7645AP/AF-1

IEC LOGIC SYMBOL

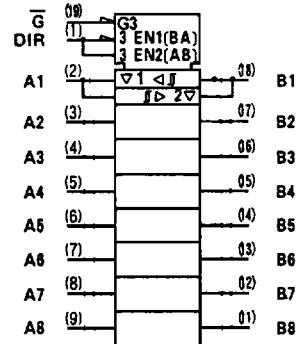
TC74HC7640A



TC74HC7643A



TC74HC7645A



TRUTH TABLE

INPUTS		FUNCTION		OUTPUTS		
\bar{G}	DIR	A BUS	B BUS	HC7640A	HC7643A	HC7645A
L	L	OUTPUT	INPUT	$A = \bar{B}$	$A = B$	$A = B$
L	H	INPUT	OUTPUT	$B = \bar{A}$	$B = \bar{A}$	$B = A$
H	X	High Impedance		Z	Z	Z

X : Don't care

Z : High impedance



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5 ~ 7	V
DC Input Voltage	V_{IN}	-0.5 ~ V_{CC} + 0.5	V
DC Output Voltage	V_{OUT}	-0.5 ~ V_{CC} + 0.5	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 35	mA
DC V_{CC} /Ground Current	I_{CC}	± 75	mA
Power Dissipation	P_D	500(DIP)*/180(SOIC)	mW
Storage Temperature	T_{STG}	-65 ~ 150	°C
Lead Temperature 10sec	T_L	300	°C

*500mW in the range of $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$. From $T_a=65^{\circ}\text{C}$ to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2 ~ 6	V
Input Voltage	V_{IN}	0 ~ V_{CC}	V
Output Voltage	V_{OUT}	0 ~ V_{CC}	V
Operating Temperature	T_{OPR}	-40 ~ 85	°C
Input Rise and Fall Time (DIR, \bar{G})	t_r, t_f	0 ~ 1000($V_{CC}=2.0\text{V}$) 0 ~ 500($V_{CC}=4.5\text{V}$) 0 ~ 400($V_{CC}=6.0\text{V}$)	ns

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	Ta=25°C			Ta=-40 ~85°C		UNIT
			V _{CC}	MIN.	TYP.	MAX.	MIN.	
High-Level Input Voltage (DIR, G)	V _{IH}		2.0	1.5	—	—	1.5	—
			4.5	3.15	—	—	3.15	—
			6.0	4.2	—	—	4.2	—
Low-Level Input Voltage (DIR, G)	V _{IL}		2.0	—	—	0.5	—	0.5
			4.5	—	—	1.35	—	1.35
			6.0	—	—	1.8	—	1.8
Positive Threshold Voltage (An, Bn)	V _P		2.0	1.0	1.25	1.5	1.0	1.5
			4.5	2.3	2.7	3.15	2.3	3.15
			6.0	3.0	3.5	4.2	3.0	4.2
Negative Threshold Voltage (An, Bn)	V _N		2.0	0.3	0.65	0.9	0.3	0.9
			4.5	1.13	1.6	2.0	1.13	2.0
			6.0	1.5	2.3	2.6	1.5	2.6
Hysteresis Voltage (An, Bn)	V _H		2.0	0.3	0.6	1.0	0.3	1.0
			4.5	0.6	1.1	1.4	0.6	1.4
			6.0	0.8	1.2	1.7	0.8	1.7
High-Level Output Voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	2.0	—	1.9
			I _{OH} = -6 mA	4.5	4.4	4.5	—	4.4
			I _{OH} = -7.8mA	6.0	5.9	6.0	—	5.9
Low-Level Output Voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	—	0.0	0.1	0.1
			I _{OL} = 6 mA	4.5	—	0.0	0.1	0.1
			I _{OL} = 7.8mA	6.0	—	0.0	0.1	0.1
3-State Output Off-State Current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND	6.0	—	—	±0.5	—	±5.0
Input Leakage Current	I _{IN}	V _{IN} = V _{CC} or GND	6.0	—	—	±0.1	—	±1.0
Quiescent Supply Current	I _{CC}	V _{IN} = V _{CC} or GND	6.0	—	—	4.0	—	40.0

μA



AC ELECTRICAL CHARACTERISTICS($C_L=50\text{pF}$, Input $t_r=t_f=6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	Ta=25°C			Ta=-40 ~ 85°C		UNIT	
			CL	V _{CC}	MIN.	TYP.	MAX.		
Output Transition Time	t_{TLH}		50	2.0	—	25	60	—	ns
	t_{THL}			4.5	—	7	12	—	
				6.0	—	6	10	—	
Propagation Delay Time	t_{pLH}		50	2.0	—	50	125	—	ns
				4.5	—	17	25	—	
				6.0	—	15	21	—	
	t_{pHL}		150	2.0	—	63	150	—	
				4.5	—	22	30	—	
				6.0	—	18	26	—	
3-State Output Enable Time	t_{pZL}	$R_L = 1\text{k}\Omega$	50	2.0	—	50	150	—	ns
				4.5	—	17	30	—	
				6.0	—	15	26	—	
	t_{pZH}		150	2.0	—	63	180	—	
				4.5	—	22	36	—	
				6.0	—	19	31	—	
3-State Output Disable Time	t_{pLZ}	$R_L = 1\text{k}\Omega$	50	2.0	—	45	150	—	ns
	t_{pHZ}			4.5	—	20	30	—	
				6.0	—	19	26	—	
Input Capacitance	C _{IN}	DIR, G			—	5	10	—	pF
Bus Input Capacitance	C _{I/O}	A _n , B _n			—	13	—	—	
Power Dissipation Capacitance	C _{PD(1)}	TC74HC7640A/7643A			—	48	—	—	
		TC74HC7645A			—	45	—	—	

Note(1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(\text{avg})} = C_{PD} \cdot V_{CC} \cdot f_N + I_{CC}/8(\text{per bit})$$